10/781,746

BRS	L13	2	(multi-threshold adj voltage) and depletion	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
BRS	L14	4	(multi-threshold adj voltage) and enhancement	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
BRS	L15	4156	flip-flop and enhancement	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
BRS	L16	34	flip-flop and (enhancement-type adj transistor)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
BRS	L17	29	16 and depletion	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB